

P CHANNEL MOSFET, -30V, 8.8A, Transistor Polarity:P Channel, Continuous Drain Current Id:-8.8A, Drain Source Voltage Vds:-30V, On Resistance Rds(on):20ohm, Rds(on) Test Voltage Vgs:-10V, Threshold Voltage Vgs:-1.7V

Manufacturers	<a href="#">ON Semiconductor, LLC</a>
Package/Case	SOIC-8
Product Type	Transistors
RoHS	Pb-free Halide free
Lifecycle	



Images are for reference only

Please submit RFQ for SI4435DY or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

## General Description

This P-Channel MOSFET is a rugged gate version of Fairchild Semiconductor's advanced PowerTrench process. It has been optimized for power management applications requiring a wide range of gate drive voltage ratings (4.5V - 25V).

## Application

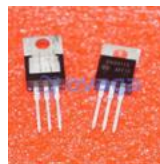
ONSEMI

## Related Products



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### [D45H11G](#)

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TO-220



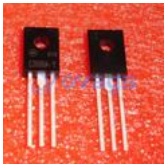
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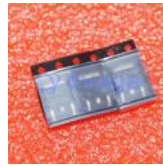
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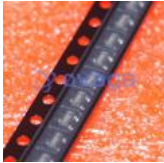
[KSC2690AYSTU](#)

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